UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO.

: 7,185,307 B2 '

APPLICATION NO.: 10/708256

DATED

: February 27, 2007

INVENTOR(S)

: Hsin-Shih Wang

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the title page item (54), and col. 1, line 1, change

"METHOD OF FABRICATING <u>AND</u> INTEGRATED CIRCUIT THROUGH UTILIZING METAL LAYERS TO PROGRAM RANDOMLY POSITIONED BASIC UNITS"

to

--METHOD OF FABRICATING <u>AN</u> INTEGRATED CIRCUIT THROUGH UTILIZING METAL LAYERS TO PROGRAM RANDOMLY POSITIONED BASIC UNITS--

Signed and Sealed this

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Eighth Day of May, 2007

JON W. DUDAS

Director of the United States Patent and Trademark Office